

isc Silicon NPN Power Transistor

DESCRIPTION

- Collector-Emitter Sustaining Voltage
 - : V_{CEO(SUS)} = 300V(Min)
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

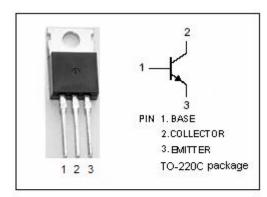
 Designed for high voltage inverters, switching regulators and line operated amplifier applications. Especially well suited for switching power supply applications

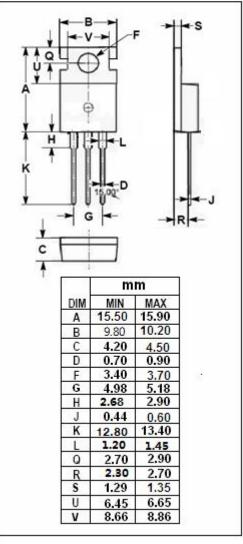
ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

ABSOLUTE MAXIMUM RATINGS(Ta-25 C)							
SYMBOL	PARAMETER	VALUE	UNIT				
V _{CBO}	Collector-Base Voltage	400	V				
V_{CEO}	Collector-Emitter Voltage	tor-Emitter Voltage 300					
V _{EBO}	Emitter-Base Voltage 6		V				
Ic	Collector Current-Continuous 5		А				
I _{CM}	Collector Current-Peak 10		Α				
I _B	Base Current-Continuous	2	А				
Pc	Collector Power Dissipation @ T _C =25°C 80		W				
TJ	Junction Temperature	150	$^{\circ}$				
T _{stg}	Storage Temperature Range	-65~150	$^{\circ}$				

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.56	°C/W







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MJE52T

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT				
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = 25mA; I _B = 0	300			٧				
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 2A			2.0	V				
V _{BE(on)}	Base-Emitter On Voltage	I _C = 5A; V _{CE} = 10V			2.0	V				
I _{CEO}	Collector Cutoff Current	V _{CE} = 200V; I _B =0			1.0	mA				
Ісво	Collector Cutoff Current	V _{CB} = 400V; I _E = 0			1.0	mA				
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C =0			1.0	mA				
h _{FE-1}	DC Current Gain	I _C = 0.3A ; V _{CE} = 10V	30							
h _{FE-2}	DC Current Gain	I _C = 5A; V _{CE} = 10V	5							
Сов	Output Capacitance	I _E = 0 ; V _{CB} = 10V; f _{test} =0.1MHz		150		pF				
Switching times										
t _{on}	Turn-On Time	I_{C} = 2.5A , I_{B1} = - I_{B2} = 0.5A $V_{BE(off)}$ = 5V; V_{CC} = 125V		0.5		μ s				
t _{off}	Turn-Off Time			2.0		μ s				

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